



PRESIDENCY UNIVERSITY

BENGALURU

Roll No.												
----------	--	--	--	--	--	--	--	--	--	--	--	--

End - Term Examinations – May / June 2026

Date: 25- 05- 2026

Time: 09:30am – 12:30pm

School: SOE	Program: B.Tech	
Course Code: PHY2503	Course Name: Fundamentals of Material Physics	
Semester: II	Max Marks: 100	Weightage: 50%

CO - Levels	CO1	CO2	CO3	CO4	CO5	CO6
Marks	12	12	14	19	17	26

Instructions:

- (i) Read all questions carefully and answer accordingly.
- (ii) Do not write anything on the question paper other than roll number.

Part A

Answer ALL the Questions. Each question carries 2marks.

10Q x 2M=20M

1.	Explain Bravais lattices. State the total number of Bravais lattices.	2 Marks	L2	CO1
2.	Explain the term degree of freedom.	2 Marks	L1	CO2
3.	Define Fermi energy.	2 Marks	L1	CO3
4.	Explain the concept of solar cell efficiency with expression.	2 Marks	L2	CO3
5.	Define strain. Explain why is strain dimensionless.	2 Marks	L2	CO4
6.	Define Poisson's ratio.	2 Marks	L1	CO4
7.	Define shear stress in fluids.	2 Marks	L1	CO5
8.	Explain the limitations of ball milling.	2 Marks	L2	CO6
9.	Explain any two properties of CNTs.	2 Marks	L2	CO6
10.	Describe graphene and its basic characteristics.	2 Marks	L2	CO6

Part B

Answer the Questions.

Total Marks 80M

11.	a.	Define Miller indices and explain the step-by-step method for finding Miller indices of a plane which makes intercepts $a, 2b$ and $3c$ with axes. Make a suitable sketch. Draw a neat diagram of the (100) and (200) planes in a cubic unit cell.	10 Marks	L3	CO1
	b.	Explain phase. Distinguish between phase and component. State Gibbs Phase Rule and explain each term briefly.	5 Marks	L2	CO2
	c.	Explain the construction of a binary phase diagram. Mention the significance of binary phase diagrams in materials engineering.	5 Marks	L2	CO2

Or

12.	a.	Explain line defects (dislocations) in crystals. Distinguish between edge dislocation and screw dislocation with suitable diagram. Distinguish between primitive unit cell and non-primitive unit cell.	10 Marks	L2	CO1
	b.	Describe an isomorphous binary system, clearly explaining: Liquidus line, Solidus line, Single-phase and two-phase regions.	5 Marks	L2	CO2
	c.	Define phase diagram. Explain the tie line and lever rule for a binary phase diagram.	5 Marks	L2	CO2

13.	a.	Explain how to determine modulus of rigidity using torsional pendulum. Two torsional pendulums have moments of inertia in ratio 1:4. Find ratio of time periods.	10 Marks	L3	CO4
	b.	Explain the influence of frequency and temperature on polarization mechanisms in dielectric materials.	5 Marks	L2	CO3
	c.	If the susceptibility of a dielectric is 0.6, calculate the polarization when the applied electric field is $3 \times 10^5 \text{ V m}^{-1}$. $\epsilon_0 = 8.854 \times 10^{-12} \text{ F}^{-1} \text{ m}^{-1}$	5 Marks	L2	CO3

Or

14.	a.	Explain the stress-strain curve with all important points. Discuss the elastic and plastic behavior of materials using stress-strain curve.	10 Marks	L3	CO4
	b.	Explain Peltier effect with diagram. Define Peltier coefficient.	5 Marks	L2	CO3
	c.	At a thermocouple junction, 180 J of heat is absorbed when a current of 5 A flows for 3 minutes. Calculate the Peltier coefficient (π) of the junction.	5 Marks	L3	CO3

15.	a.	Explain the continuum hypothesis and discuss its validity in engineering applications. Classify fluids based on viscosity and compressibility with suitable examples.	10 Marks	L2	C05
	b.	Explain the no-slip condition. Discuss its importance in fluid flow problems with practical examples.	5 Marks	L2	C05
	c.	Explain the assumptions made in the theory of simple bending.	5 Marks	L2	C04
Or					
16.	a.	Mention Newton's law of viscosity and explain its physical significance. Explain Newtonian and non-Newtonian fluids with examples.	10 Marks	L2	C05
	b.	A plate in a machine is lubricated by a film of SAEOW oil at 200C with thickness $t=1.5$ mm. The plate has a length $L=30$ mm and depth $w=130$ mm (into the page). Calculate the shear force (F) required to slide the plate at a velocity $v=2.1$ m/s. Dynamic viscosity of oil is 0.86 kg/m.s ² .	5 Marks	L3	C05
	c.	Explain bending moment and shear force for a beam. Mention the relation between them.	5 Marks	L2	C04

17.	a.	Explain the effect of nanoscale size on material properties such as mechanical, optical, electrical, and chemical properties with examples. Explain the significance of surface to volume ratio here.	10 Marks	L2	C06
	b.	Differentiate between top-down and bottom-up approaches of nanomaterial synthesis.	5 Marks	L2	C06
	c.	An XRD pattern shows broad peaks. Analyze the reason for peak broadening and explain how crystallite size is determined.	5 Marks	L3	C06
Or					
18.	a.	Explain the principle and working of X-ray Diffraction (XRD). Discuss how it is used to determine crystal structure.	10 Marks	L2	C06
	b.	For X-ray of wavelength $1.54 \text{ \AA}$, find interplanar spacing if diffraction occurs at $\theta = 30^\circ$.	5 Marks	L3	C06
	c.	Given a requirement for high purity and controlled size nanomaterials, select a suitable synthesis method and justify your choice with reasoning.	5 Marks	L3	C06